









CEF10N65

650V A 710mΩ A 10ANote 4 A Si MOSFET

SILICON Si MOSFET ▲ THT type
N-channel enhancement mode
UL94V-0 rated flame retardant epoxy

TO220F-3L package ▲ Electrical insulated mounting tab

Super high dense cell density for extremely low R_{DS(ON)}

High power and current handling capability

MAXIMUM RATINGS

| Parameter (T _C = 25°C, unless otherwise noted) | | Characteristics |
|---|-----------------------------------|-----------------|
| Drain-Source Voltage | V _{DS} | 650V |
| Gate-Source Voltage | V _{GS} | ±30V |
| Continuous Drain Current at T _C = 25°C | I _D | 10A Note 4 |
| Continuous Drain Current at T _C = 100°C | I _D | 6A Note 4 |
| Pulsed Drain Current Note 1 | I _{DM} Note 5 | 40A Note 4 |
| Maximum Power Dissipation at $T_c = 25^{\circ}C$ | P _D | 60W |
| Power Dissipation Derating above 25°C | ΔP_D | 0.4W/°C |
| Single Pulsed Avalanche Energy Note 6 | E _{AS} | 554mJ |
| Single Pulsed Avalanche Current Note 6 | I _{AS} | 4.3A |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55°C to +175°C |

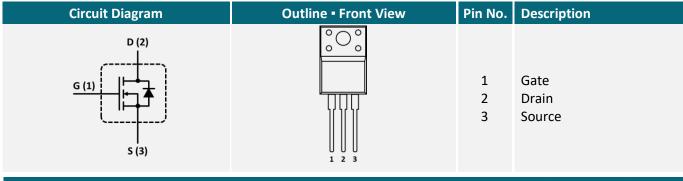
THERMAL CHARACTERISTICS

| Parameter | Symbol | Limit |
|---|--------------------|---------|
| Thermal Resistance, Junction-to-Case | R _{TH_JC} | 2.5°C/W |
| Thermal Resistance, Junction-to-Ambient | R _{TH JA} | 65°C/W |

APPLICATIONS

| EV Charging | Industrial Inverters | Motors & Drives | Power Factor Correction | Renewable Energy | SMPS | UPS |
|----------------|-------------------------|--------------------|----------------------------|---------------------|------|-----|
| ₹ | | | PFC | * | | |

PIN DESCRIPTION





ELECTRICAL CHARACTERISTICS ▲ T_C = 25°C, unless otherwise noted

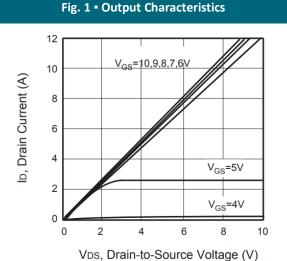
| ltem | Condition | Symbol | Min. | Тур. | Max. | Unit |
|--|--|---------------------|------|------|------|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0V$, $I_D = 250\mu A$ | BV_DSS | 650 | | | V |
| Zero Gate Voltage Drain Current | $V_{DS} = 650V, V_{GS} = 0V$ | I _{DSS} | | | 1 | μΑ |
| Zero Gate Voltage Drain Current | $V_{DS} = 520V$, $V_{GS} = 0V$, $T_{C} = 125$ °C | I _{DSS} | | | 10 | μΑ |
| Gate Body Leakage Current, Forward | $V_{GS} = 30V, V_{DS} = 0V$ | I _{GSSF} | | | 100 | nA |
| Gate Body Leakage Current, Reverse | $V_{GS} = -30V$, $V_{DS} = 0V$ | I _{GSSR} | | | -100 | nA |
| On Characteristics Note 2 | | | | | | |
| Gate Threshold Voltage | $V_{GS} = V_{DS}$, $I_D = 250 \mu A$ | $V_{GS(th)}$ | 2 | | 4 | V |
| Static Drain-Source On-Resistance | $V_{GS} = 10V, I_D = 5A$ | R _{DS(ON)} | | 710 | 850 | mΩ |
| Dynamic Characteristics Note 3 | | | | | | |
| Input Capacitance | $V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$ | C _{ISS} | | 1540 | | pF |
| Output Capacitance | $V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$ | Coss | | 185 | | pF |
| Reverse Transfer Capacitance | $V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$ | C_{RSS} | | 15 | | pF |
| Switching Characteristics Note 3 | | | | | | |
| Turn-On Delay Time | V_{DD} = 300V, V_{GS} = 10V, I_{D} = 10A, $R_{G(ext)}$ = 25 Ω | t _{D(ON)} | | 36 | | ns |
| Turn-On Rise Time | V_{DD} = 300V, V_{GS} = 10V, I_D = 10A, $R_{G(ext)}$ = 25 Ω | t_R | | 38 | | ns |
| Turn-Off Delay Time | V_{DD} = 300V, V_{GS} = 10V, I_D = 10A, $R_{G(ext)}$ = 25 Ω | t _{D(OFF)} | | 106 | | ns |
| Turn-Off Fall Time | V_{DD} = 300V, V_{GS} = 10V, I_D = 10A, $R_{G(ext)}$ = 25 Ω | t _F | | 32 | | ns |
| Total Gate Charge | $V_{DS} = 480V$, $V_{GS} = 10V$, $I_D = 10A$ | Q_{G} | | 35 | | nC |
| Gate Source Charge | $V_{DS} = 480V$, $V_{GS} = 10V$, $I_D = 10A$ | Q_{GS} | | 7.3 | | nC |
| Gate Drain Charge | $V_{DS} = 480V$, $V_{GS} = 10V$, $I_D = 10A$ | Q_{GD} | | 14.3 | | nC |
| Drain-Source Diode Characteristics a | nd Maximum Ratings | | | | | |
| Drain-Source Diode Forward Current | | I _S | | | 6 | Α |
| Drain-Source Diode Forward Voltage Note 2 | $V_{GS} = 0V$, $I_S = 6A$ | V_{SD} | | | 1.4 | V |

Notes

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature
- 2: Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 3: Guaranteed by design, not subject to production testing.
- 4: Limited only by maximum temperature allowed.
- 5: Pulse width limited by safe operating area.
- 6: L = 60mH, $I_{AS} = 4.3A$, $V_{DD} = 50V$, $R_G = 25\Omega$, Starting $T_J = 25^{\circ}C$



REFERENCE DATA A TYPICAL DEVICE PERFORMANCE



12 10 8 8 6 4 2 25°C 0 0 2 4 6 8 10

Fig. 2 • Transfer Characteristics

Fig. 3 - Capacitance

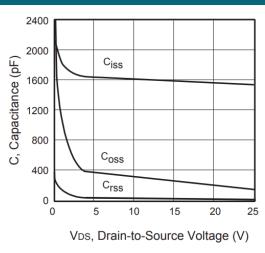


Fig. 4 • On-Resistance Variation with Temperature

Vgs, Gate-to-Source Voltage (V)

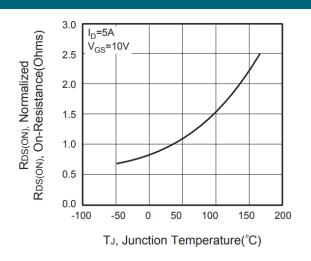


Fig. 5 • Gate Threshold Variation with Temperature

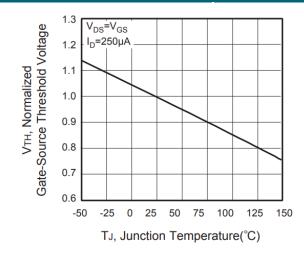
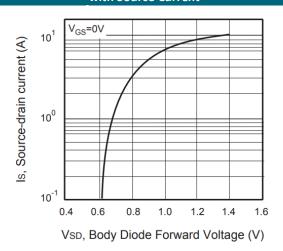


Fig. 6 • Body Diode Forward Voltage Variation with Source Current





REFERENCE DATA A TYPICAL DEVICE PERFORMANCE

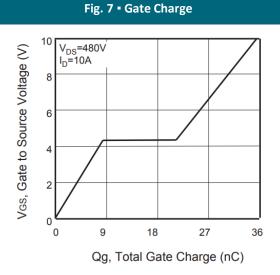


Fig. 8 • Maximum Safe Operating Area

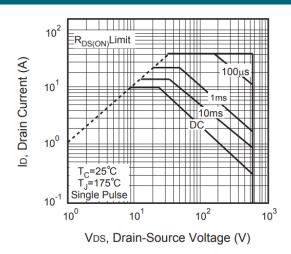
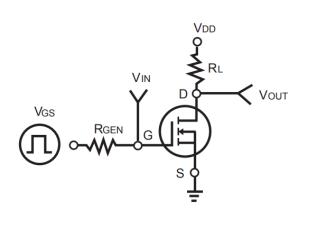


Fig. 9 • Switching Test Circuit

Fig. 10 • Switching Waveforms



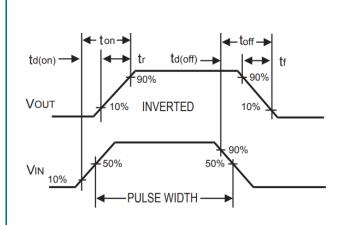
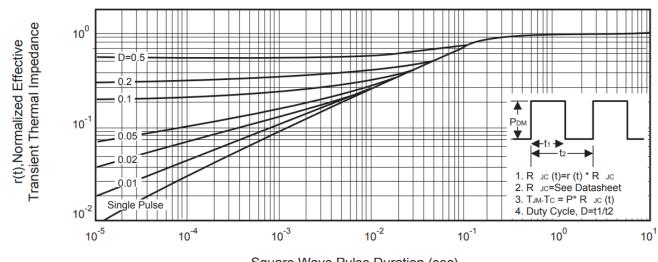


Fig. 11 - Normalized Thermal Transient Impedance Curve

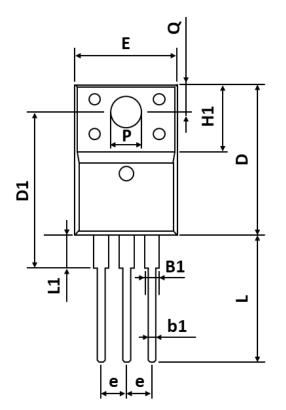


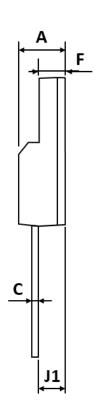
Square Wave Pulse Duration (sec)

MGT ▲ Manufacturer Group of Technology



PACKAGE OUTLINE





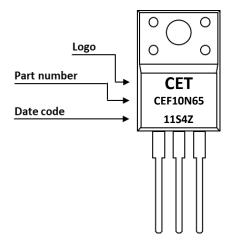
| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|--------------------|--------------------|--------------------|
| Α | 4.500 | - | 5.000 |
| B1 | 1.000 | - | 1.500 |
| b1 | 0.700 | - | 0.950 |
| С | 0.420 | - | 0.700 |
| D | 15.670 | - | 16.070 |
| D1 | 14.800 | - | 16.000 |
| E | 9.960 | - | 10.360 |
| е | 2.340 | - | 2.740 |
| F | 2.340 | - | 2.740 |
| H1 | 6.480 | - | 6.900 |
| J1 | 2.550 | - | 2.950 |
| L | 12.080 | - | 13.480 |
| L1 | 2.230 | - | 3.650 |
| Q | 3.100 | - | 3.500 |
| Р | 2.980 | - | 3.380 |

ORDERING INFORMATION

| Part Number | Package | Packing | Tube Qty. | Inner Box Qty. | Outer Box Qty. |
|-------------|------------|---------|-----------|----------------|----------------|
| CEF10N65 | TO-220F-3L | Tube | 50pcs | 1,000pcs | 4,000pcs |

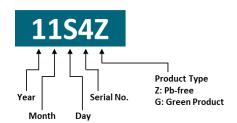


PART MARKING



DATE CODE

Example: 11S4Z



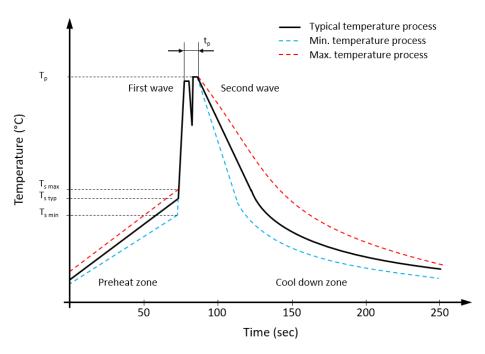


Coding list for "Day"





RECOMMENDED WAVE SOLDERING PROFILE A THT PACKAGE



Classification wave soldering profile ▲ Refer to EN 61760-1: 2006

| Profile Features | | Value ▲ Sn-Pb Assembly | Value ▲ Pb-free Assembly |
|--|--------------------|---|--|
| Preheat temperature min. | T_{smin} | 100 °C | 100 °C |
| Preheat temperature typical | T _{s typ} | 120 °C | 120 °C |
| Preheat temperature max. | T_{smax} | 130 °C | 130 °C |
| Preheat time t_s from T_{smin} to T_{smax} | ts | 70 seconds | 70 seconds |
| Peak temperature | T_p | 235 °C to 260 °C | 245 °C to 260 °C |
| Time of actual peak temperature | t _p | Max. 10 seconds Max. 5 second each wave | Max. 10 seconds Max. 5 second each wave |
| Ramp-down date min. | | ~ 2 °C/second | ~ 2 °C/second |
| Ramp-down rate typical | | ~ 3.5 °C/second | ~ 3.5 °C/second |
| Ramp-down rate max. | | ~ 5 °C/second | ~ 5 °C/second |
| Time 25°C to 25°C | | 4 minutes | 4 minutes |



REVISION TABLE

| Revision | Date | Status | Notes |
|----------|------------|-----------------|---------------------|
| 001 | 30/09/2022 | Initial release | Initial publication |
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